COMPLIANT

HALOGEN FREE



Vishay General Semiconductor

High Current Density Surface-Mount Schottky Barrier Rectifier

eSMP[®] Series

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 6 A			
V_{RRM}	40 V			
I _{FSM}	150 A			
E _{AS}	20 mJ			
V _F at I _F = 6 A	0.40 V			
T _J max.	125 °C			
Package	SMPC (TO-277A)			
Circuit configuration	Common cathode			

FEATURES

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency
- · Low thermal impedance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

MECHANICAL DATA

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3_X - halogen-free, RoHS-compliant and

AEC-Q101 qualified

("_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

PARAMETER		SYMBOL	SS12P4C	UNIT
Device marking code			S124C	
Maximum repetitive peak reverse voltage		V_{RRM}	40	V
Maximum average forward rectified current (fig. 1) (1)	total device	I _{F(AV)}	12	А
	per diode		6.0	
Maximum average forward rectified current (2)	total device	I _{F(AV)}	3.5	Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150	А
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode		E _{AS}	20	mJ
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, at T_J = 25 $^{\circ}$ C per diode		I _{RRM}	1.0	А
Operating junction and storage temperature range		T _{J,} T _{STG}	-55 to +125	°C

Notes

- (1) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink
- (2) Free air, mounted on recommended copper pad area



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 1 A	T _A = 25 °C	A = 25 °C	0.34	-	V	
	I _F = 3 A			0.40	-		
	I _F = 6 A			0.46	0.52		
	I _F = 1 A	T _A = 100 °C	'	v F ()	0.24	-	
	I _F = 3 A				0.31	-	
	I _F = 6 A			0.40	0.45		
Reverse current per diode	Rated V _R	T _A = 25 °C T _A = 100 °C	T _A = 25 °C	I _R ⁽²⁾	129	500	μΑ
	nated V _R		IR (-)	11.9	25	mA	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	400	-	pF	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width $\leq 40 \text{ ms}$

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL SS12P4C		UNIT	
Typical thermal resistance	R _{0JA} (1)	100	°C/W	
	R _{0JM} (2)	3		

Notes

- $^{(1)}$ Free air, mounted on recommended copper pad area. Thermal resistance $R_{\theta JA}$ junction to ambient
- (2) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink. Thermal resistance R_{θJM} junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS12P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel	
SS12P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel	
SS12P4CHM3_A/H (1)	0.10	Н	1500	7" diameter plastic tape and reel	
SS12P4CHM3_A/I (1)	0.10	I	6500	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

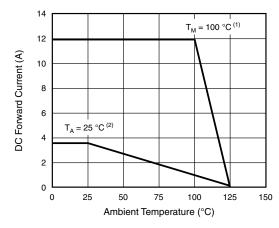


Fig. 1 - Maximum Forward Current Derating Curve

Notes

- Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink, T_M measured at the terminal of cathode band (R_{θJM} = 3 °C/W)
- Free air, mounted on recommended copper pad area $(R_{\theta JA} = 100 \, ^{\circ}\text{C/W})$



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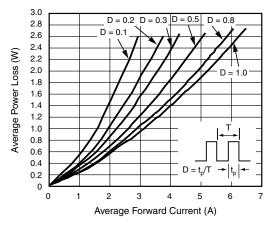


Fig. 2 - Forward Power Loss Characteristics Per Diode

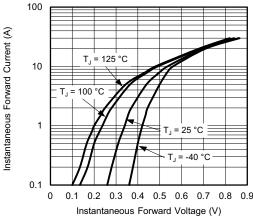


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

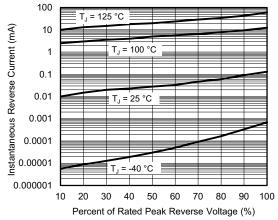


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

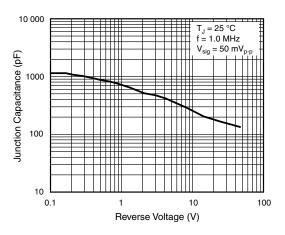


Fig. 5 - Typical Junction Capacitance Per Diode

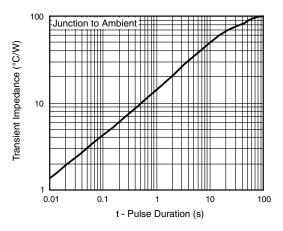
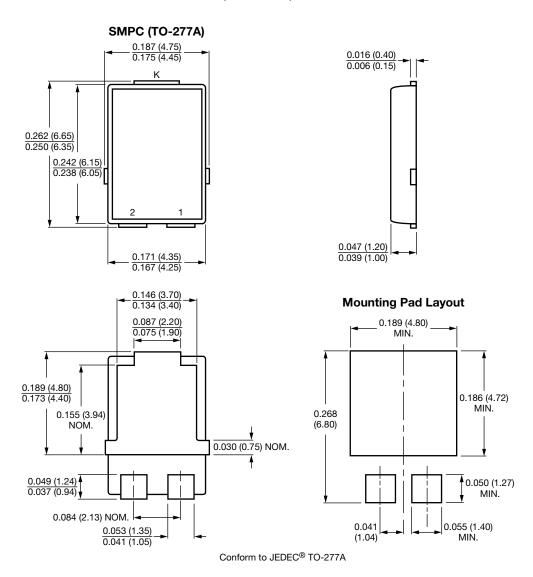


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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